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Bib Data Sheet

**CONFIRMATION NO. 5622** 

Junichi Sato, Tokyo, JAPAN; Setsuo Usui, Kanagawa, JAPAN; Yasuhiro Sakamoto, Kanagawa, JAPAN; Yoshifumi Mori, Chiba, JAPAN; Hideharu Nakajima, Kanagawa, JAPAN;  *** CONTINUING DATA **********************************	DID Data Sheet						<u> </u>	
Junichi Sato, Tokyo, JAPAN; Setsuo Usui, Kanagawa, JAPAN; Yasuhiro Sakamoto, Kanagawa, JAPAN; Yasuhiro Sakamoto, Kanagawa, JAPAN; Yoshifumi Mori, Chiba, JAPAN; Hideharu Nakajima, Kanagawa, JAPAN;  "CONTINUING DATA "**  "FOREIGN APPLICATIONS ***  JAPAN P2000-269298 09/05/2000 JAPAN P2000-269297 09/05/2000 JAPAN P2000-269219 09/05/2000 JAPAN P2000-269210 90/05/2000 JAPAN P2000-269218 90/05/2000 JAPAN P2000-269210 90/05/2000		DATE 04/21/2004	CLASS GROUP AR			DOCKET NO.		
Setsuo Usui, Kanagawa, JAPAN; Yasuhiro Sakamoto, Kanagawa, JAPAN; Yoshifurni Mori, Chiba, JAPAN; Hideharu Nakajima, Kanagawa, JAPAN;  "CONTINUING DATA ***  This application is a DIV of 09/946,898 09/05/2001 PAT 6,746,942  "FOREIGN APPLICATIONS ***  JAPAN P2000-269274 09/05/2000 JAPAN P2000-269274 09/05/2000 JAPAN P2000-269274 09/05/2000 JAPAN P2000-269274 09/05/2000 JAPAN P2000-269271 09/05/2000 JAPAN P2000-269271 09/05/2000 JAPAN P2001-244163 08/10/2001  IF REQUIRED, FOREIGN FILING LICENSE GRANTED  ***09/02/2004  Foreign Priority claimed	APPLICANTS							
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